|   |             | GUJARAT TECHNOLOGICAL UNIVERSITY  |         |  |
|---|-------------|---|---------|--|
| G1-3  | ~ ~ 4       | BE- SEMESTER-I & II(NEW)EXAMINATION – SUMMER 2022   | 2022    |  |
| Subj  | ect         | Code:5110018 Date:04-08-  | -2022   |  |
| Time:10:30 AM TO 01:00 PM Total Ma<br>Instructions: |             |   | arks:70 |  |
| 111501 0  | 1.<br>2.    | Attempt all questions.<br>Make suitable assumptions wherever necessary.   |         |  |
|   | 3.<br>4.    | Figures to the right indicate full marks.<br>Simple and non-programmable scientific calculators are allowed.  | Marks   |  |
| 0.1   | <b>(a)</b>  | What is physical significance of the negative effective mass?   | 03      |  |
| ¥   | (b)         | Find the probability of an electron occupying an energy level 0.02 eV above the Fermi level at 200 K and 400 K in a material.   | 04      |  |
|   | (c)         | Derive an expression for electrical and thermal conductivity in a material and hence verify Wiedemann-Franz law.  | 07      |  |
| Q.2   | (a)         | Show that for an intrinsic semiconductor the Fermi level lies at the middle of the energy gap.  | 03      |  |
|   | (b)         | The intrinsic carrier density of given semiconductor is $1.5 \times 10^{16} \text{ m}^{-3}$ . If the mobility of the electrons and holes are 0.13 and 0.05 m <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> respectively, calculate the conductivity. | 04      |  |
|   | (c)         | Obtain an expression for concentration of holes in valance band in intrinsic semiconductor.   | 07      |  |
|   | (c)         | Derive the formula for concentration of electrons in conduction band in n-<br>type semiconductor.   | 07      |  |
| Q.3   | (a)         | Write the difference between spontaneous emission and stimulated emission.  | 03      |  |
|   | <b>(b</b> ) | Explain Ohmic junction with necessary diagram.  | 04      |  |
|   | (c)         | What do you mean by joint density of state? Derive mathematical expression for optical joint density of states.   | 07      |  |
| Q.3   | (a)         | Write short note on exciton.  | 03      |  |
|   | (b)         | If the light having wavelength of 4000 A° falls on semiconductor having bandgap of 2.1 eV. Assuming mass of electron in conduction band and   | 04      |  |
|   |             | valance band is same as rest mass of electron, calculate the optical joint density of states for given semiconductor  |         |  |
|   | (c)         | For bulk semiconductor show that the ratio of Einstein's co-efficient is directly proportional to cube of frequency.  | 07      |  |
| Q.4   | (a)         | Write the drawbacks of two probe method.  | 03      |  |
|   | (b)         | An n-type Ge sample has donor density of $10^{21}$ m <sup>-3</sup> . It is arranged in a Hall effect experiment having $B_z = 0.5$ Wb/m <sup>2</sup> and $J_x = 500$ A/m <sup>2</sup> . Find Hall voltage if the width of sample is 3 mm.           | 04      |  |
|   | (c)         | What is Hall effect? Obtain expressions for Hall Voltage and Hall mobility.   | 07      |  |

|     |              | OR   |          |
|-----|--------------|--|----------|
| Q.4 | (a)<br>(b)   | Explain Hot point probe measurement.<br>A 20.0 mm wide and 1.0 mm thick silver strip is placed in 1.5 Wb/m <sup>2</sup> magnetic field in such a way that magnetic field remains perpendicular to strip. A current of 200 A is set-up in the strip. Calculate the Hall voltage of the strip. (given: $n = 8.4 \times 10^{28} \text{ m}^{-3}$ ) | 03<br>04 |
|     | ( <b>c</b> ) | Explain Current-Voltage characteristic of Solar cell.  | 07       |
| Q.5 | (a)          | Define: (1) Critical Temperature (2) Critical Magnetic field (3) Critical  | 03       |
|     | (b)          | For specimen of V <sub>3</sub> Ga, the critical fields are $1.4 \times 10^5$ A/m and $4.2 \times 10^5$ A/m at 14 K and 13 K respectively. Calculate the value of transition temperature.   | 04       |
|     | (c)          | Write and explain characteristics of superconductors.  | 07       |
| Q.5 | ( <b>a</b> ) | The critical temperature for Hg with isotopic mass 199.5 is 4.185 K.<br>Calculate its critical temperature when its isotopic mass changes to 203.4.  | 03       |
|     | <b>(b)</b>   | Write the difference between Type-I and Type-II superconductor.  | 04       |
|     | (c)          | Explain BCS theory.  | 07       |
|     |              | atton Par  |          |

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